

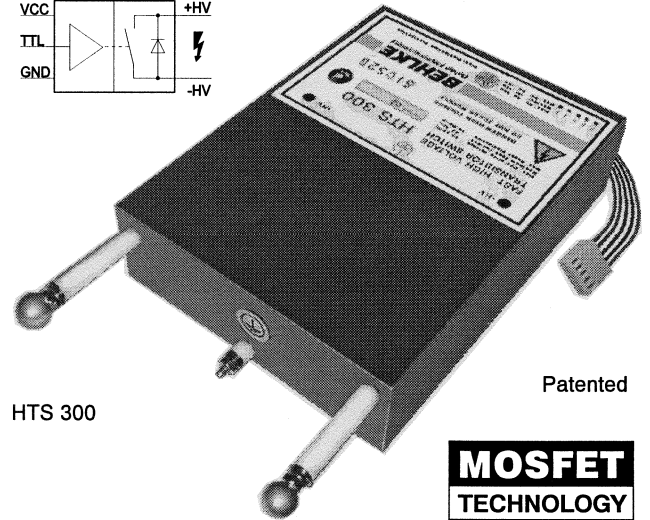
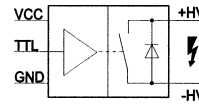
# FAST HIGH VOLTAGE TRANSISTOR SWITCHES

These solid-state switches generate precise high-voltage pulses with amplitudes of up to 65 kV as needed for example in pulsed electrostatic deflection and acceleration systems. The models HTS 300 and HTS 650 will preferably be used to generate high voltage pulses with a very fast leading edge and a highly stable and ripple-free voltage pulse top, but without special requirements regarding the trailing edge.

In contrast to conventional high-voltage switches like gas discharge tubes or electron tubes, HTS switches do not need heating power or complex drive circuitries. They show a very short recovery time, a low jitter and a lifetime typical for semiconductor devices. The power part of the switching modules is made up of a large number of MOSFET connected in parallel and in series which are absolutely synchronously controlled by a special driver. Due to the galvanic isolation the devices can be used as high-side switches for positive as well as for negative voltages. The modules are protected from thermal overload by means of an internal temperature sensor. Further protection is afforded against too high a signal frequency and insufficient auxiliary supply. All fault conditions will be indicated at the fault signal output (pin 4) as a logical "Low" signal. At the same time the switch will be turned off until correct operating conditions are ensured.

The on-time of the standard models is fixed at 200 nanoseconds. On-time extensions of 1, 10 and 100 microseconds as well as customized on-time extensions are available as built-in options. In connection with these options the switches can also be retrigged within their burst capability which allows an on-time variation in certain limits. The turn-off rise time of switches with on-time extension option roughly corresponds to the preceding on-time. As a result of that considerable switching losses may arise, especially at low load resistances. Therefore the working resistors should not be chosen smaller than some 10 kOhm if on-time options are used. For detailed design recommendations please refer to the instructions.

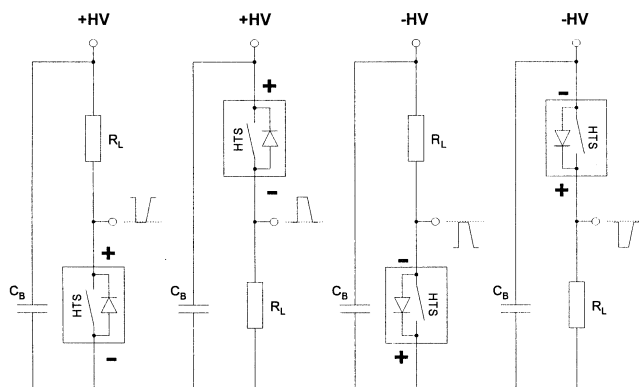
**HTS 300** 30 kVDC / 30 A (pk)  
**HTS 650** 65 kVDC / 30 A (pk)



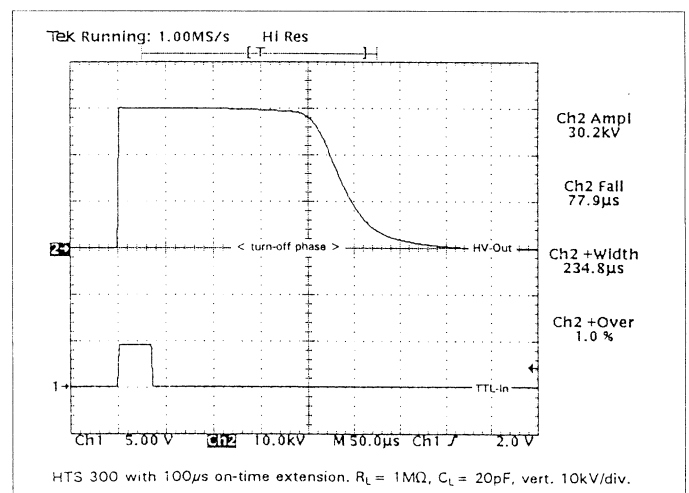
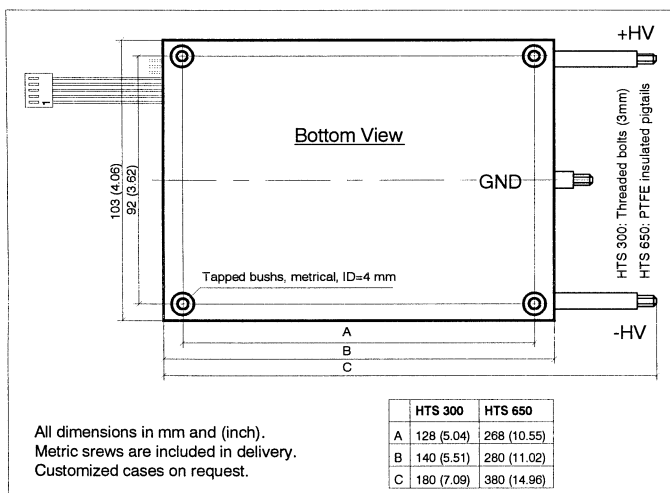
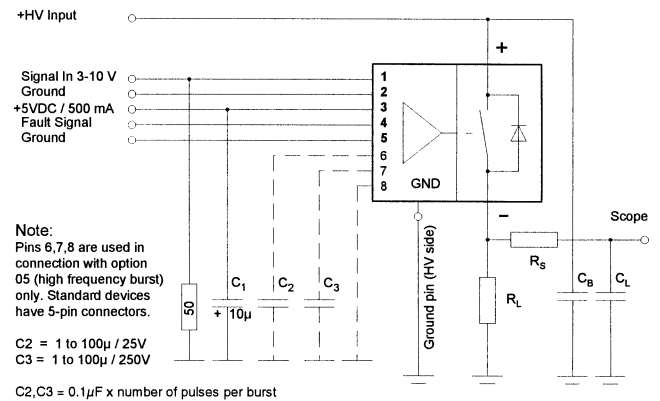
HTS 300

**Fixed On-Time**  
 for extremely low noise & uncritical EMC

## Basic Circuits



## Test Circuit (High-Side Switch)



# TECHNICAL DATA

Specification	Symbol	Condition / Comment	HTS 300	HTS 650	Unit
Maximum Operating Voltage	$V_{O(max)}$		± 30	± 65	kVDC
Minimum Operating Voltage	$V_{O(min)}$	$t_{r(on)}$ is increased significantly below 10% of $V_{O(max)}$		0	VDC
Switch Breakdown Voltage	$V_{br}$	$I_{off} = 1 \text{ mADC}$ , $T_{case}=70^\circ\text{C}$	>33	>72	kVDC
Isolation Voltage	$V_I$	Switch against ground / control	>40	>85	kVDC
Maximum Peak Current	$I_{P(max)}$	$t_p < 10\mu\text{s}$ , duty cycle < 1%		30	ADC
Static On-Resistance	$R_{stat}$	Single pulse/ $T_{case}=25^\circ\text{C}$	68	144	$\Omega$
		$I_L = 0.1 \times I_{P(max)}$ $I_L = 1.0 \times I_{P(max)}$	170	360	
Maximum Off-State Current	$I_{off}$	$0.8 \times V_O$		<10	$\mu\text{ADC}$
Turn-On Delay Time	$t_{d(on)}$	$0.8 \times V_O$ , $C_L=20\text{pF}$ , $R_S=51\Omega$	110	125	ns
Turn-On Rise Time	$t_{r(on)}$	$R_L=1\text{M}\Omega$	15	70	ns
		$R_S=51\Omega$	60	120	
		$0.8 \times V_O$ , $C_L=20\text{pF}$ $0.8 \times V_O$ , $C_L=100\text{pF}$ $0.8 \times V_O$ , $C_L=250\text{pF}$	110	135	
Turn-Off Rise Time	$t_{r(off)}$	Standard devices without on-time extension		0.03	$\mu\text{s}$
		With option 01		~1	
		With option 02		~10	
		With option 03		~100	
On-Time (=Pulse Duration)	$t_{on}$	Standard devices without on-time extension, on-time tolerance ± 10%	150	200	ns
		With option 01, on-time tolerance -10,+30%		1	$\mu\text{s}$
		With option 02, on-time tolerance -10,+30%		10	
		With option 03, on-time tolerance -10,+30%		100	
		With option 04, customized on-time		Any value from 0.1 to 200	
Typical Turn-On Jitter	$t_{j(on)}$	$V_{aux}=5.0 \text{ VDC}$ , $V_{tr}=5\text{VDC}$		100	ps
Maximum Burst Frequency	$f_{b(max)}$	Burst option required for > 20 pulses / 20 $\mu\text{s}$		2	MHz
Maximum Continuous Frequency	$f_{c(max)}$	@ $V_{aux}=5.00\text{VDC}$ , note $P_{d(max)}$ limitations	10	3	kHz
Max. Continuous Power Dissipation	$P_{d(max)}$	$T_{case}=25^\circ\text{C}$ , standard plastic case	20	25	Watts
Linear Derating above 25°C			0.44	0.55	W/°C
Temperature Range	$T_O$	Extended temperature range on request		-30 to +70	°C
Natural Switch Capacitance	$C_N$	Capacitance between switch poles at $V_{O(max)}$	18	25	pF
Coupling Capacitance	$C_C$	Capacitance between switch and ground	30	50	pF
Diode Reverse Recovery Time	$t_{rrc}$	@ $I_F=6\text{A}$ , $di/dt=100\text{A}/\mu\text{s}$		500	ns
Diode Forward Voltage	$V_{SD}$	@ $I_F=6\text{A}$ , single pulse 10 $\mu\text{s}$	51	108	VDC
Auxiliary Supply Voltage	$V_{aux}$	Stabilized to ± 5%		5	VDC
Auxiliary Supply Current	$I_{aux}$	@ $f_{Cmax}$		400	mADC
Trigger Signal Voltage	$V_{tr}$			3-10	VDC
Fault Signal Output Voltage		„Low“ in case of overfrequency, overtemperature or bad auxiliary supply. @ 1mA output current.		„High“ ≥ 4.0 „Low“ ≤ 0.8	VDC
Fault Signal Output Current		Source current (High), short circuit proof		5	mADC
		Sink current (Low), short circuit proof		10	
Dimensions		Case only, see drawing	140x102x35	280x102x35	mm <sup>3</sup>
Weight			830	1570	g

## Ordering Information

<b>HTS 300</b>	Transistor switch, 30 kV	<b>Option 04</b>	Customized on-time, up to 200 $\mu\text{s}$
<b>HTS 650</b>	Transistor switch, 65 kV	<b>Option 05</b>	High frequency burst
<b>Option 01</b>	On-time extension, ~1 $\mu\text{s}$ , fixed	<b>Option 06</b>	UL-94-VO casting resin
<b>Option 02</b>	On-time extension, ~10 $\mu\text{s}$ , fixed	<b>Option 07</b>	Increased thermal conductivity
<b>Option 03</b>	On-time extension, ~100 $\mu\text{s}$ , fixed	<b>Option 08</b>	High power metal case (integrated oil cooling)